

## Product Overview

### FSB649: NPN Low Saturation Transistor

For complete documentation, see the data sheet.

These devices are designed with high current gain and low saturation voltage with collector currents up to 3 A continuous. Sourced from Process NC.

### Applications

- This product is general usage and suitable for many different applications.

### Part Electrical Specifications

Product	Pricing (\$/Unit)	Compliance	Status	Polarity	Type	$V_{CE(sat)Max}$ (V)	$I_C$ Cont. (A)	$V_{CEO Min}$ (V)	$V_{CBO}$ (V)	$V_{EBO}$ (V)	$V_{BE(sat)}$ (V)	$V_{BE(on)}$ (V)	$h_{FE Min}$	$h_{FE Max}$	$f_T$ Min (MHz)	$P_{TM Max}$ (W)	Package Type
FSB649	0.1471	Pb-free Halide free non AEC-Q and PPAP	Active	NPN	Low $V_{CE(sat)}$	0.6	3	25	35	5	1.25	1	100	300	150	0.5	SOT-23-3

For more information please contact your local sales support at [www.onsemi.com](http://www.onsemi.com).

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